TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74AC08P, TC74AC08F, TC74AC08FN, TC74AC08FT

OUAD 2-INPUT AND **GATE**

The TC74AC08 is an advanced high speed CMOS 2-INPUT AND GATE fabricated with silicon gate and double - layer metal wiring C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 2 stages including buffer output, which provide high noise immunity and stable output. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

- High Speed------t_{pd} = 3.4ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ··········· $I_{CC} = 4\mu A(Max.)$ at Ta = 25°C
- High Noise Immunity $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Symmetrical Output Impedance -- | I_{OH} | = I_{OL} = 24mA(Min.)

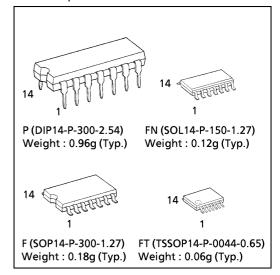
Capability of driving 50Ω transmission lines.

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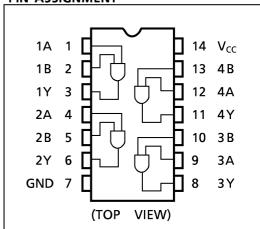
• Balanced Propagation Delays $\cdots t_{pLH} \approx t_{pHL}$

- Wide Operating Voltage Range ···· V_{CC} (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74F08

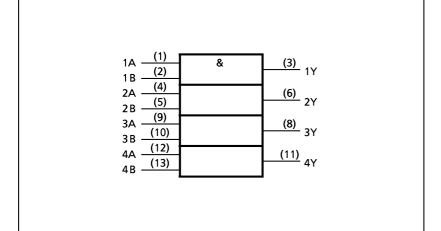
(Note) The JEDEC SOP (FN) is not available in Japan.



PIN ASSIGNMENT



IEC LOGIC SYMBOL



TRUTH TABLE

Α	В	Υ
L	L	L
L	Н	L
Н	L	Ĺ
Н	Н	Н

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	٧
DC Input Voltage	V _{IN}	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I _{IK}	± 20	mΑ
Output Diode Current	I _{OK}	± 50	mΑ
DC Output Current	I _{OUT}	± 50	mA
DC V _{cc} /Ground Current	I _{cc}	± 100	mA
Power Dissipation	P _D	500 (DIP)* / 180 (SOP/TSSOP)	mW
Storage Temperature	T _{stg}	−65~150	°C

*500mW in the range of Ta = -40° C ~65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{cc}	2.0~5.5	V
Input Voltage	V _{IN}	0~V _{CC}	٧
Output Voltage	V _{OUT}	0~V _{CC}	V
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	dt/dV	$0 \sim 100 \text{ (Vcc} = 3.3 \pm 0.3 \text{V)}$ $0 \sim 20 \text{ (Vcc} = 5 \pm 0.5 \text{V)}$	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER SYMBOL		TEST CONDITION		V _{CC} 7		Га = 25°C		Ta = -40~85°C		UNIT
				(V)	MIN.	TYP.	MAX.	MIN.	MAX.	OIVIII
High - Level Input Voltage	VIH		2.0 3.0 5.5	1.50 2.10 3.85	111		1.50 2.10 3.85		٧	
Low - Level Input Voltage	VIL		2.0 3.0 5.5	_ 	_ _ _	0.50 0.90 1.65	_ _ _	0.50 0.90 1.65	٧	
High - Level	.,,	V V	$I_{OH} = -50\mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	_ _ _	1.9 2.9 4.4	_ _ _	.,,
Output Voltage	V он	$V_{IN} = V_{IH}$	$I_{OH} = -4mA$ $I_{OH} = -24mA$ $I_{OH} = -75mA*$	3.0 4.5 5.5	2.58 3.94 —	_ _ _	_ _ _	2.48 3.80 3.85	_ _ _	\
Low - Level	V	V _{I N} =	$I_{OL} = 50 \mu A$	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	.,
Output Voltage	VOL	V _{IH} or V _{IL}	$I_{OL} = 12mA$ $I_{OL} = 24mA$ $I_{OL} = 75mA*$	3.0 4.5 5.5	111	111	0.36 0.36 —	_ _ _	0.44 0.44 1.65	\ \ \ \ \
Input Leakage Current	I _{IN}	$V_{IN} = V_{CC}$ or GND		5.5	ı	_	±0.1	_	± 1.0	
Quiescent Supply Current	I _{cc}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	_	40.0	μ A

^{* :} This spec indicates the capability of driving 50Ω transmission lines. One output should be tested at a time for a 10ms maximum duration.

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF , $\,R_L$ = 500 Ω , Input $\,t_r$ = t_f = 3ns)

		TEST CONDITION		Ta = 25°C			Ta = -40~85°C		
PARAMETER	SYMBOL	1231 6311311	V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
Propagation Delay Time	t _{pLH} t _{pHL}		3.3 ± 0.3 5.0 ± 0.5		5.8 4.5	9.8 7.0	1.0 1.0	11.3 8.0	ns
Input Capacitance	C _{IN}			_	5	10	_	10	ne
Power Dissipation Capacitance	C _{PD} (1)			_	71	_	_	_	pF

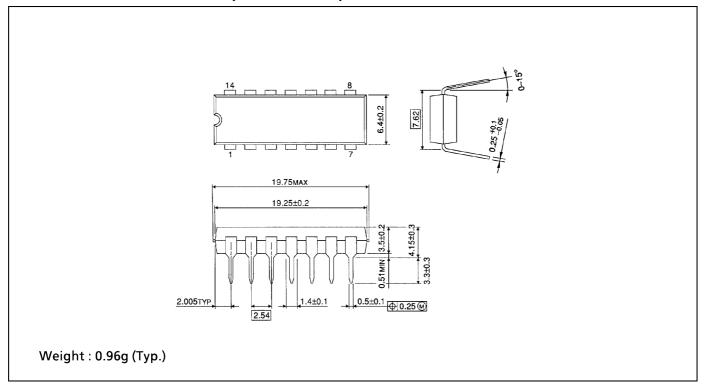
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4 \text{ (per Gate)}$$

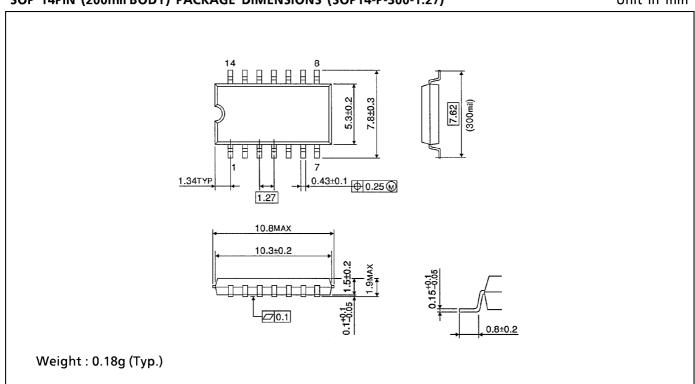
DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)

Unit in mm



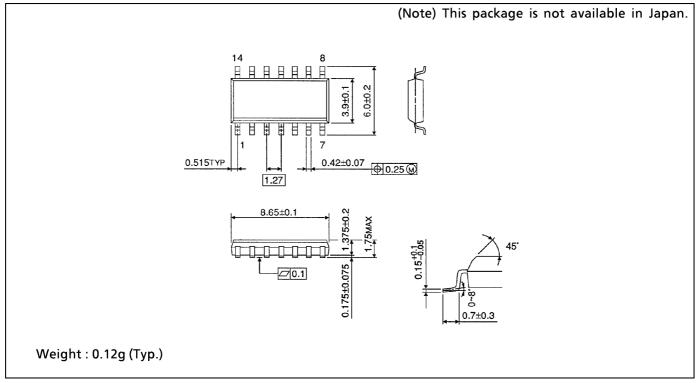
SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

Unit in mm



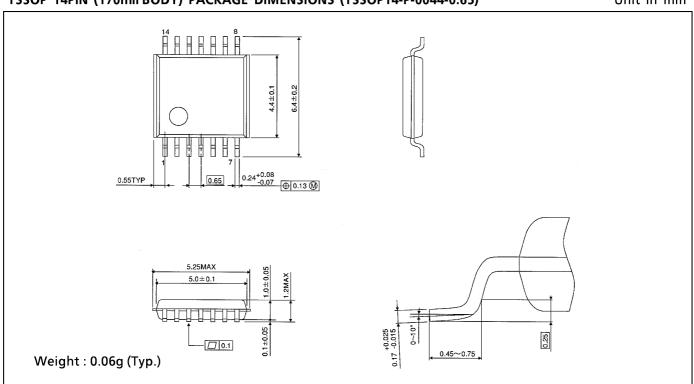
SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150 -1.27)

Unit in mm



TSSOP 14PIN (170mil BODY) PACKAGE DIMENSIONS (TSSOP14-P-0044-0.65)

Unit in mm



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2001-05-17

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